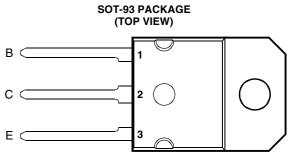
30URNS®

BD745, BD745A, BD745B, BD745C NPN SILICON POWER TRANSISTORS

- Designed for Complementary Use with the • **BD746 Series**
- 115 W at 25°C Case Temperature
- 20 A Continuous Collector Current •
- 25 A Peak Collector Current
- **Customer-Specified Selections Available**



Pin 2 is in electrical contact with the mounting base. MDTRAAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	BD745		50	
Collector-base voltage (I _E = 0)	BD745A	V	70	v
	BD745B	V _{CBO}	90	v
	BD745C		110	
Collector-emitter voltage (I _B = 0)	BD745		45	
	BD745A	N	60	v
	BD745B	V _{CEO}	80	v
	BD745C		100	
Emitter-base voltage	V _{EBO}	5	V	
Continuous collector current			20	A
Peak collector current (see Note 1)	I _{CM}	25	A	
Continuous base current		I _B	7	A
Continuous device dissipation at (or below) 25°C case temperature (see Note	P _{tot}	115	W	
Continuous device dissipation at (or below) 25°C free air temperature (see No	P _{tot}	3.5	W	
Unclamped inductive load energy (see Note 4)	½Ll _C ²	90	mJ	
Operating free air temperature range	T _A	-65 to +150	°C	
Operating junction temperature range		Тj	-65 to +150	°C
Storage temperature range		T _{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds	TL	260	°C	

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$. 2. Derate linearly to 150°C case temperature at the rate of 0.92 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 0.4 A, R_{BE} = 100 Ω , $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = 20 V$.

PRODUCT INFORMATION

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electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS			MIN	ТҮР	MAX	UNIT			
V _{(BR)CEO}	Collector-emitter breakdown voltage	Ū.	I _B = 0	(see Note 5)	BD745 BD745A BD745B BD745C	45 60 80 100			V
I _{CBO}	Collector cut-off current	$V_{CE} = 110 V$ $V_{CE} = 50 V$ $V_{CE} = 70 V$ $V_{CE} = 90 V$ $V_{CE} = 110 V$	$V_{BE} = 0$	T _C = 125°C T _C = 125°C T _C = 125°C T _C = 125°C T _C = 125°C	BD745 BD745A BD745B BD745C BD7455 BD745A BD745B BD745B BD745C			0.1 0.1 0.1 5 5 5 5	mA
I _{CEO}	Collector cut-off current	$V_{CE} = 30 V$ $V_{CE} = 60 V$	$I_B = 0$ $I_B = 0$		BD745/745A BD745B/745C			0.1 0.1	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	$I_{\rm C} = 0$					0.5	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$ $V_{CE} = 4 V$		(see Notes 5 a	und 6)	40 20 5		150	
V _{CE(sat)}	Collector-emitter saturation voltage		I _C = 20 A	(see Notes 5 and 6)				1 3	V
V _{BE}	Base-emitter voltage	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_{\rm C} = 5 \text{ A}$ $I_{\rm C} = 20 \text{ A}$	(see Notes 5 and 6)				1 3	V
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 1 A	f = 1 kHz		25			
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 1 A	f = 1 MHz		5			

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \ \mu s$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER			ТҮР	MAX	UNIT
R _{0JC} Junction	to case thermal resistance			1.1	°C/W
R _{0JA} Junction	to free air thermal resistance			35.7	°C/W

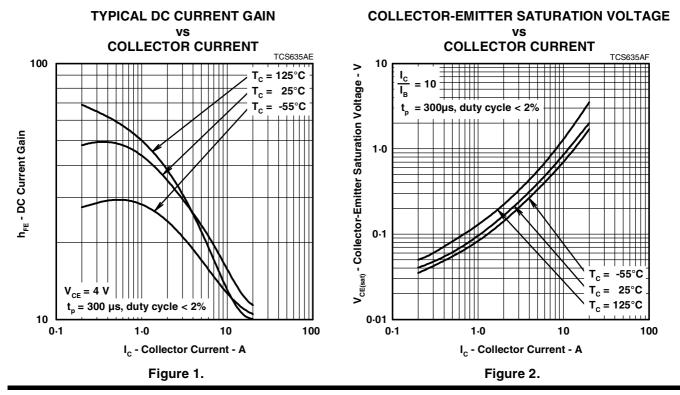
resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _d	Delay time					20		ns
t _r	Rise time	I _C = 5 A	$I_{B(on)} = 0.5 A$	$I_{B(off)} = -0.5 A$		350		ns
t _s	Storage time	V _{BE(off)} = -4.2 V	$R_L = 6 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		500		ns
t _f	Fall time					400		ns

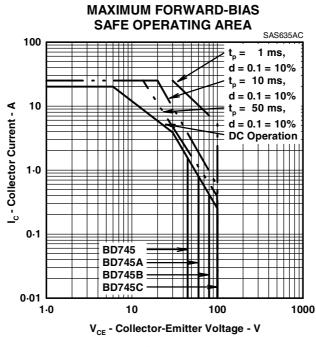
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS









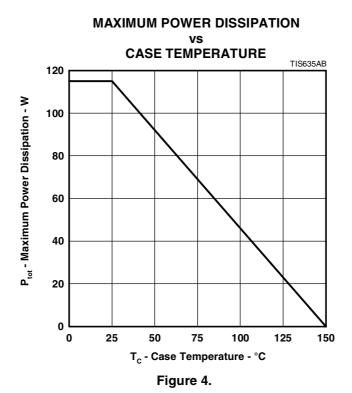
PRODUCT INFORMATION

AUGUST 1978 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.

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THERMAL INFORMATION





Mouser Electronics

Authorized Distributor

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